Developing SiC for Optical System Applications

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Motivation

- Silicon carbide is a new material with potential for making large lightweight mirrors and systems quickly and costeffectively
- Is this material ready for insertion into future systems, especially in space systems?
- How do we characterize and develop this material for future needs?



Outline

- Space application requirements
- Existing material overview
- Why SiC?
- SiC descriptions
- Evolution of SiC from substrate to system material
- Future work
- Recommendations
- Summary



Space Application Needs and Goals

- Build large aperture mirrors
 - Apertures >3 m in diameter are of interest
 - Low areal density, currently \approx 15kg/m2, goal 1 5 kg/m2
- Choose materials that maintain optical performance from launch through on-orbit operations
 - Radiation environment
 - Maintain optical performance even with radiation exposure: AO, UV, electrons, micro debris etc
 - Develop model to predict behavior
 - Material and structural stability
 - Maintain optical performance during launch and temperature variations on orbit
- Reduce risk by using material with extensive space heritage
 - Rely on engineering experience
 - Design systems using established design trades
- Reduce cost of developing new space materials
 - Develop cost-effective substrate production, optical finishing, and coatings
 - Perform space environment testing



Low CTE Mirror Materials

- Glass
 - Fused silica
 - ULE
 - Zerodur
- Metals
 - Beryllium
- Alternatives
 - Composites
 - SiC



- Source: Stephen Jacobs, SPIE Vol 1335
- Operating parameters dictate material selection

-Room temperature, Zerodur and ULE good choices

-Cryogenic temperatures, less than 123K, fused silica may be better choice

Glass vs Be vs SiC

Glass

- Extensive space heritage
- Easily figured and polished
- Long lead times for large-diameter applications
- Be
 - Space heritage, used for structures and mirrors
 - Established material, proven longterm stability
 - Uncertain supply and challenges of toxicity
- SiC

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- High thermal conductivity, low thermal expansion, high specific stiffness, can be lightweighted
- Multiple suppliers, inexpensive substrates
- Good potential for space applications
- Limited space heritage and difficult to polish to an optical surface luona A Per



Source: Trex Enterprises

- All materials are susceptible to radiation effects to varying extents
 - Materials have a change in density
 - Compaction or expansion can occur
 - Changes can affect radius of curvature



Choosing SiC: Systems engineering approach

- Using a single property to choose a material must be avoided, must examine all parameters and application
- Evaluate replacement of existing materials with SiC on case-by-case basis
 - May not be possible to replace only one component of a system with SiC
 - Decision may require reengineering of entire system
 - Introduction of SiC may be more successful in new projects and technology developments
- Resistance may exist when replacement of well-known components with higher risk materials is suggested
 - Reengineering and unknown performance



SiC Mirrors vs. Structures

- Complete SiC system is passively athermal instrument
 - Challenges in mounting and assembly of system
 - Inserts, bonding, SiC screws
- Somewhat different requirements for mirror vs structures
 - Solution is application driven
- Structures
 - High fracture toughness
 - Specific stiffness may not need to be as high
 - Require more weight (Fiber reinforced)
 - Uniformity not as critical, if high fracture toughness is key
- Mirrors
 - High specific stiffness, enables lightweighting
 - Polishable, create optical surface
 - High uniformity, maintain optical performance

Mirrors and structures may require two

different forms of SiC



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SiC Production Methods

- Chemical Vapor Deposition (CVD): fully dense single-phase SiC, zero porosity
- Sintering: trace amounts of a second phase from sintering, porosity 2 – 5%
- Reaction bonding: two-phase mixture of SiC and silicon metal (6 to 40%), porosity 0 – 15%
- Graphite or carbon conversion: single-phase (monolithic) structure with porosity up to 20%; if carbon fibers, unconverted Gr or C, or Si present, at least two-phase material
- Hot Isostatic Pressing (HIP): fully dense SiC with minor amounts of a second phase from additive used as a hot pressing aid, porosity <1%
- Foam: fully distributed load paths under mirror surface, easier metrology mount, higher stiffness and first mode frequency, porosity 85 – 95%



Porosity and Contamination

- Open Pores
 - Increased probability of contamination during fabrication
 - Migration and deposition of outgassed contaminants in vacuum
 - Onto optical surface(s) during coating process
 - Onto critical telescope components (e.g. focal plane arrays) on orbit
- Closed pores
 - Trapped gasses
 - Surface deformation due to pressure difference between fabrication and vacuum/on-orbit environments



SiC Phase Descriptions and Optical Challenges

- SiC can come in different phases
 - Single phase: pure SiC
 - Two-phase: SiC plus Si
 - Three phase: carbon fibers, SiC, Si example: CeSiC
- SiC with different phases make optical finishing a challenge
 - Single phase is a hard surface, difficult to polish
 - Two phase is more difficult to polish as SiC and Si polish at different rates requiring CVD coating for optic quality
 - Three phase can have fiber print through



Processing Challenges

- CVD: time to create monolithic part, limit on size
- Sintering: press-limited size, green body integrity during machining, controlled shrinkage during sintering, brazing required for large diameter parts
- Reaction bonding: polishing, mold quality
- HIP: expensive, limit on shapes
- Graphite or Carbon conversion: complete conversion, green body integrity during machining, multiple phases
- Foam: polishing optical surfaces, scaling to large diameters
- Different methods produce slightly differing SiC properties, which can vary up to 20% in value
- Greatest difference among manufacturing methods is costs and processes to make an optical part



US SiC Manufacturers



Source: CoorsTek



Source: M Cubed



Source: POCO



Source: SSG

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Source: Schafer



Source: Trex







Source: Xinetics Iwona.A.Palusinski@aero.org

Evolution of SiC from Substrate to System Material

- Collaborate with multiple agencies to qualify materials
 - NASA, AFRL, MDA
 - Share resources, develop multi-application requirements
- Verify consistency of SiC production
- Space qualify SiC not only as substrate material but as a system material
 - Develop mirror substrate and structural samples
 - Test variety of SiC such as reaction bonded, sintered, foams, and three phase materials
 - Investigate both coated and uncoated SiC substrates
 - Perform radiation, thermal, and vacuum testing
- Downselect to optimal forms of SiC via testing
- Develop polishing and coating technology
 - Techniques will be SiC-type dependent





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Testing and Future Work



Photo courtesy of NASA/MSFC



Drawing courtesy of AFRL/ML

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- Characterize SiC as a substrate and structural material
 - Perform material and optical testing
 - 2-stage test matrix
 - Screening most critical properties: CTE, stiffness
 - Characterization full materials testing
 - Reduce cost of materials development
 - Identify manufacturers with greatest potential early
 - Invest consolidated funds into companies that meet space environment requirements
 - Pursue SiC system development
 - Perform space environment testing
 - Earth simulation of atomic oxygen, radiation effects
 - On-orbit testing, combined effects
 - Develop and validate models of radiation effects on SiC
 - Compare on-ground orbit simulation with on-orbit exposure



Recommendations

- Continue funding development of various forms of SiC
- Encourage collaboration with various government agencies and non-profit organizations for independent evaluation of SiC
- Develop groundwork for development of established polishing and coating techniques, will vary with SiC type
- Characterize various forms of SiC from material, optical, and structural perspective
- Fund demonstration program that uses a SiC system
 - Validate material, optical, and structural characteristics of SiC
 - Produce multiples of a system to validate production processes
 - Increase diameters to meter class or greater



Summary

- SiC has attractive qualities for space applications
- Several US SiC manufacturers producing various forms of SiC
- US programs are interested in pursuing SiC as an alternate material
- SiC must evolve from substrate material to systems
 engineering material for full implementation
- Develop radiation effects modeling
 - Required to predict behavior of future systems

